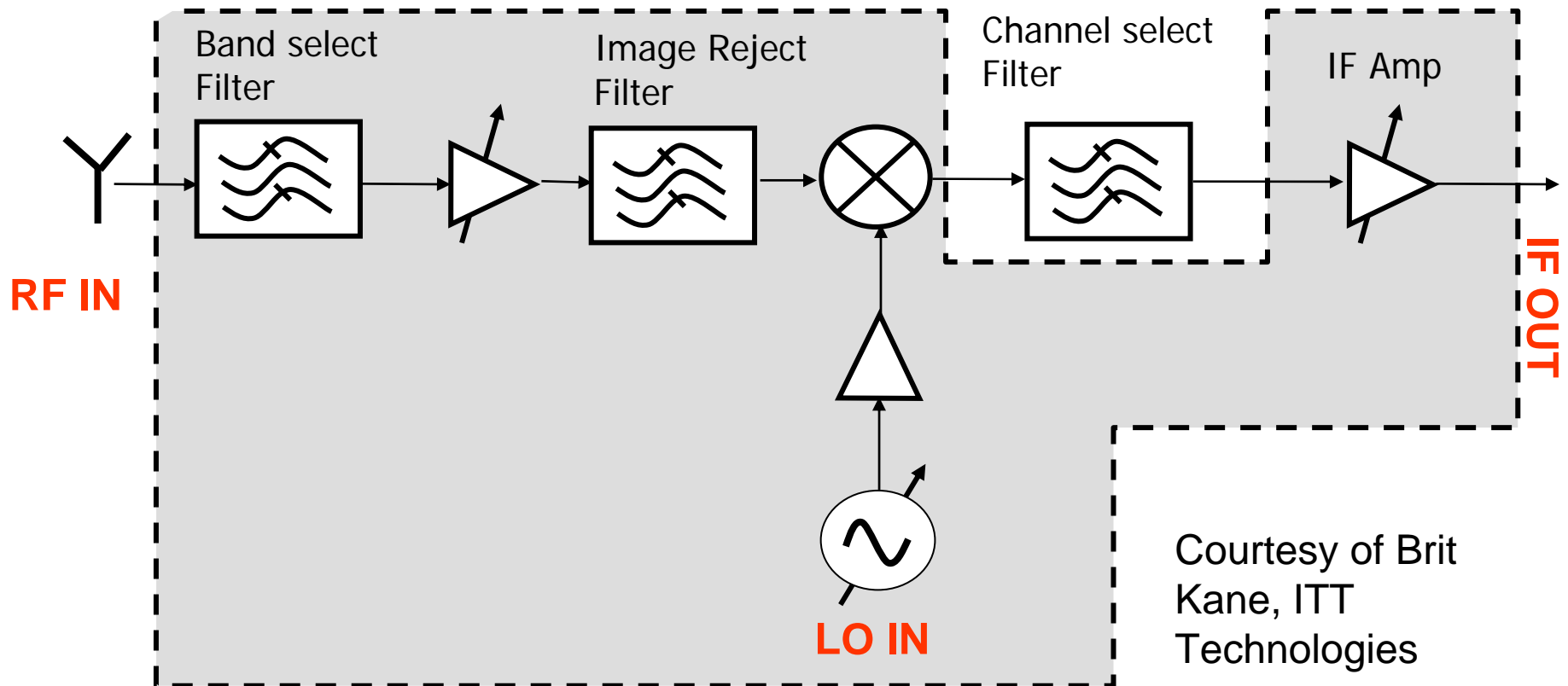


# Amplifiers

# Amplifiers

- Overview
- Performance Parameters: Low Noise & High Power
- Design and Technology Issues
- Design Approach – Low Noise Amplifiers
- Conclusions - Impact on System Design

# Overview



# Performance Parameters

## Low Noise Amplifier

ZEL-1724LN

50Ω

1700 to 2400 MHz

### Features

- very low noise, 1.5 dB max.
- wideband, 1700 to 2400 MHz
- rugged shielded case

### Applications

- PCS/DCS
- UMTS
- communication systems



CASE STYLE: EEE132

| Connectors | Model      | Price        | Qty.  |
|------------|------------|--------------|-------|
| SMA        | ZEL-1724LN | \$274.95 ea. | (1-9) |

### Low Noise Amplifier Electrical Specifications

| MODEL NO.  | FREQUENCY (MHz) |                | NOISE FIGURE (dB) | GAIN (dB) |               | MAXIMUM POWER (dBm)       |                   | INTERCEPT POINT (dBm) | VSWR (:1) Max. |     | DC POWER      |                   |
|------------|-----------------|----------------|-------------------|-----------|---------------|---------------------------|-------------------|-----------------------|----------------|-----|---------------|-------------------|
|            | f <sub>L</sub>  | f <sub>U</sub> |                   | Min.      | Flatness Max. | Output (1 dB Compr.) Typ. | Input (no damage) |                       | In             | Out | Volt (V) Nom. | Current (mA) Max. |
| ZEL-1724LN | 1700            | 2400           | 1.5               | 20        | ±1.0          | +8                        | +13               | +22                   | 2.5            | 2.5 | 15            | 70                |

Noise Figure specified at room temperature, increases to 2 dB typical at +85°C

Open load is not recommended, potentially can cause damage.

With no load derate max input power by 20 dB

### Maximum Ratings

Operating Temperature -54°C to 85°C

Storage Temperature -55°C to 100°C

DC Voltage +17V Max.

# Performance Parameters

## Coaxial Amplifier

**ZHL-10W-2G+**  
**ZHL-10W-2G**

50Ω High Power 10W 800 to 2000 MHz

### Features

- high power, 10 Watt
- low current consumption, 4A typ.
- useable over 700 to 2200 MHz
- internal power regulator (current remains constant over 22 to 28V)
- no damage with an open or short output load under full CW output power

### Applications

- cellular, PCN, GSM, ISM
- lab test



ZHL-10W-2GX+

ZHL-10W-2G(+)

CASE STYLE: BT1204

| Connectors | Model         | Price     | Qty.  |
|------------|---------------|-----------|-------|
| <b>SMA</b> | ZHL-10W-2G(+) | \$1295.00 | (1-9) |
| <b>SMA</b> | ZHL-10W-2GX+  | \$1220.00 | (1-9) |

+ RoHS compliant in accordance  
with EU Directive (2002/95/EC)

The +Suffix identifies RoHS Compliance. See our web site  
for RoHS Compliance methodologies and qualifications.

### Electrical Specifications

| MODEL NO.     | FREQ. (MHz)    |                | GAIN (dB) |      |      |               | MAXIMUM POWER OUTPUT (dBm) |      |                    |      |                   |  | DYNAMIC RANGE |                | VSWR (:1) Typ. |     | DC POWER**    |                  |
|---------------|----------------|----------------|-----------|------|------|---------------|----------------------------|------|--------------------|------|-------------------|--|---------------|----------------|----------------|-----|---------------|------------------|
|               |                |                |           |      |      |               |                            |      |                    |      |                   |  |               |                |                |     |               |                  |
|               | f <sub>L</sub> | f <sub>U</sub> | Min.      | Typ. | Max. | Flatness Max. | (1 dB Compr.) Min.         | Typ. | (3 dB Compr.) Min. | Typ. | Input (no damage) |  | NF (dB) Typ.  | IP3 (dBm) Typ. | In             | Out | Volt (V) Nom. | Current (A) Max. |
| ZHL-10W-2G(+) | 800            | 2000           | 40        | 43   | 49   | ±2.0          | +39                        | +40  | +40                | +41  | +1                |  | 7.0           | +50            | 1.3            | 1.3 | 24            | 5.0              |
| ZHL-10W-2GX** | 800            | 2000           | 40        | 43   | 49   | ±2.0          | +39                        | +40  | +40                | +41  | +1                |  | 7.0           | +50            | 1.3            | 1.3 | 24            | 5.0              |

\*Heat sink and fan not included

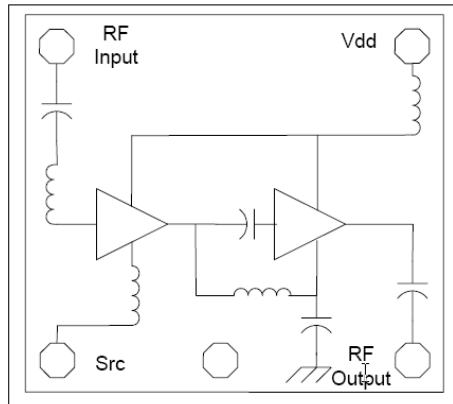
\*\* Power Supply should be capable of delivering 6A at start up.

To order without heat sink and fan, add suffix X to model number. Alternative heat sinking and heat removal must be provided by the user to limit maximum base-plate temperature to 75°C, in order to ensure proper performance. For reference, this requires thermal resistance of user's external heat sink to be 0.08°C/W Max.

### Maximum Ratings

# Performance Parameters

**Functional Block Diagram**



## Features

- 4.9 to 5.9 GHz Frequency Coverage
- Low Noise Figure
- High Gain
- Low Current: 8mA Typical @ 3V
- 50-ohm Input and Output Match
- GaAs pHEMT Technology
- Leadless 1.3 x 2.0 x 0.4 mm Lead-Free SMT Package

## Selected Specifications

| Parameter                        | min  | typ | Max  | units |
|----------------------------------|------|-----|------|-------|
| Frequency Range                  | 4900 | -   | 5900 | MHz   |
| Noise Figure (with onchip match) |      | 1.3 |      | dB    |
| Small Signal Gain                | 16.5 | 18  |      | dB    |
| Input Power (IP1dB)              |      | -13 |      | dBm   |
| Input IP3                        |      | -3  |      | dBm   |

## Applications

- 802.11a WLAN
- PCs and Mobile Devices
- WLAN Access Points
- WLAN Repeaters

# Performance Parameters



## Advance Product Information

WIRELESS COMMUNICATIONS DIVISION

Preliminary: Subject to change without notice

### 3V HBT TDMA Power Amplifier IC

**TQ7625**

#### Selected Electrical Characteristics

Test Conditions:  $V_{CC} = +3.5V$ ,  $T_C = 25^\circ C$ ,  $V_{BIAS} = 2.75V$

| Parameter  | Min.                     | Typ. | Max. | Units     |
|--|--------------------------|------|------|-----------|
| Usable Frequency Range                             | 1850                     |      | 1910 | MHz       |
| TDMA Output Power                                  |                          | 28   |      | dBm       |
| TDMA Power Added Efficiency                        |                          | 40   |      | %         |
| ACP, $P_{out} = +28$ dBm                           |                          | -30  |      | dBc       |
| ALT, $P_{out} = +28$ dBm                           |                          | -53  |      | dBc       |
| Large Signal Gain                                  |                          | 27.5 |      | dB        |
| Small Signal Gain ( $V_{mode} = \text{low}$ )      |                          | 26   |      | dB        |
| Receive Band Noise                                 |                          | -92  |      | dBm/30KHz |
| Quiescent Current,<br>uses $V_{mode}$<br>Switching | $V_{mode} = \text{low}$  | 60   |      | mA        |
|  | $V_{mode} = \text{high}$ | 80   |      | mA        |
| $V_{mode}$ , Externally<br>Switched.               | $P_{OUT} \leq +15$ dBm   | 0    | 0    | V         |
|  | $P_{OUT} = +28$ dBm      | 2.65 | 2.75 | V         |
| Second Harmonic, $P_{OUT} = +28$ dBm               |                          | -45  |      | dBc       |
| Third Harmonic, $P_{OUT} = +28$ dBm                |                          | -55  |      | dBc       |

#### Primary Application(s)

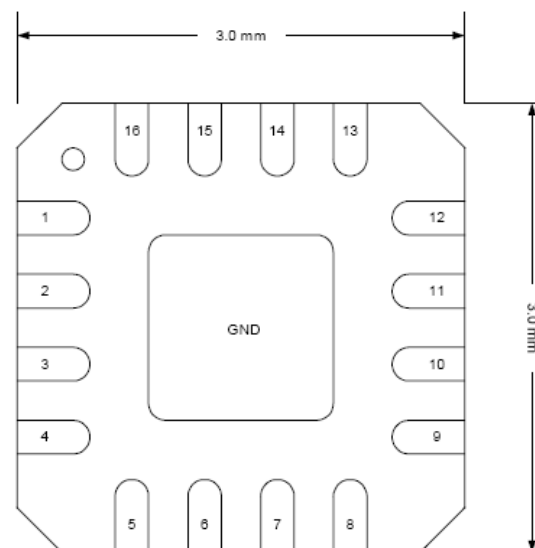
- IS-136 Mobile Phones
- Dual Band Mobile phones

**Package: 3x3 mm**

Leadless 16 pin

#### Key Features

- High Efficiency
- Low Quiescent Current,  
Mode Selectable
- Small size 3x3 mm leadless packag
- Few external components
- Excellent ACP Performance
- Single +2.7V Supply



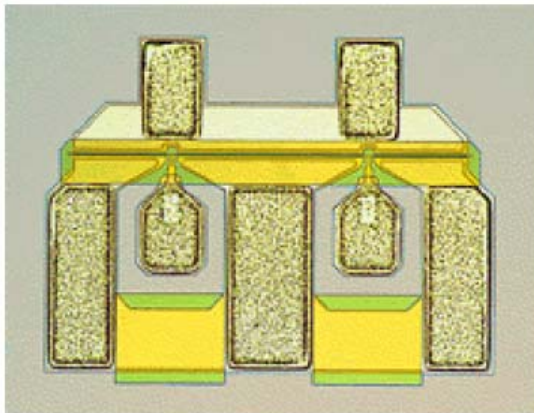
# Performance Parameters



**Product Data Sheet**  
February 1, 2002

## Discrete MESFET

## TGF1350-SCC



### Key Features and Performance

- 0.5  $\mu\text{m}$  x 300  $\mu\text{m}$  FET
- 1.5 dB Noise Figure with 11dB Associated Gain at 10 GHz
- 2.5 dB Noise Figure with 7 dB Associated Gain at 18 GHz
- All-Gold Metallization for High Reliability
- Recessed Gate Structure
- 0.620 x 0.514 x 0.102 mm (0.024 x 0.020 x 0.004 in.)



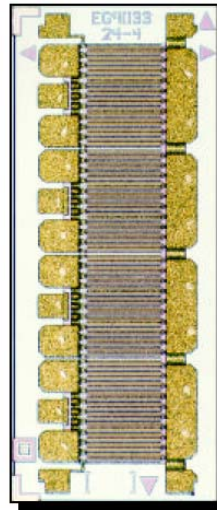
# Performance Parameters

TGF4124-EPU

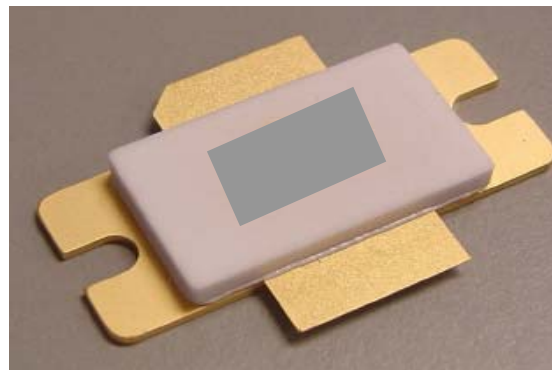
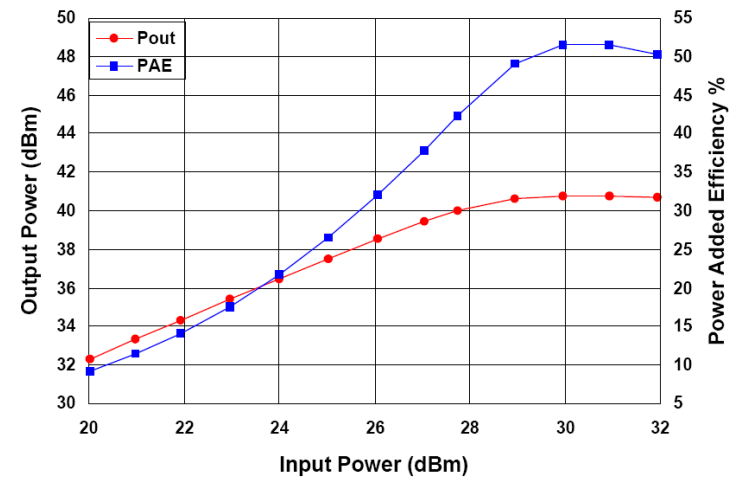
24 mm Discrete HFET

# 4124

- 0.5  $\mu\text{m}$  gate finger length
- Nominal Pout of 12 Watts at 2.3 GHz
- Nominal PAE of 51.5% at 2.3 GHz
- Nominal Gain of 10.8 dB at 2.3 GHz
- Die size 36.0 x 81.0 x 4.0 mils  
(0.914 x 2.057 x 0.102 mm)



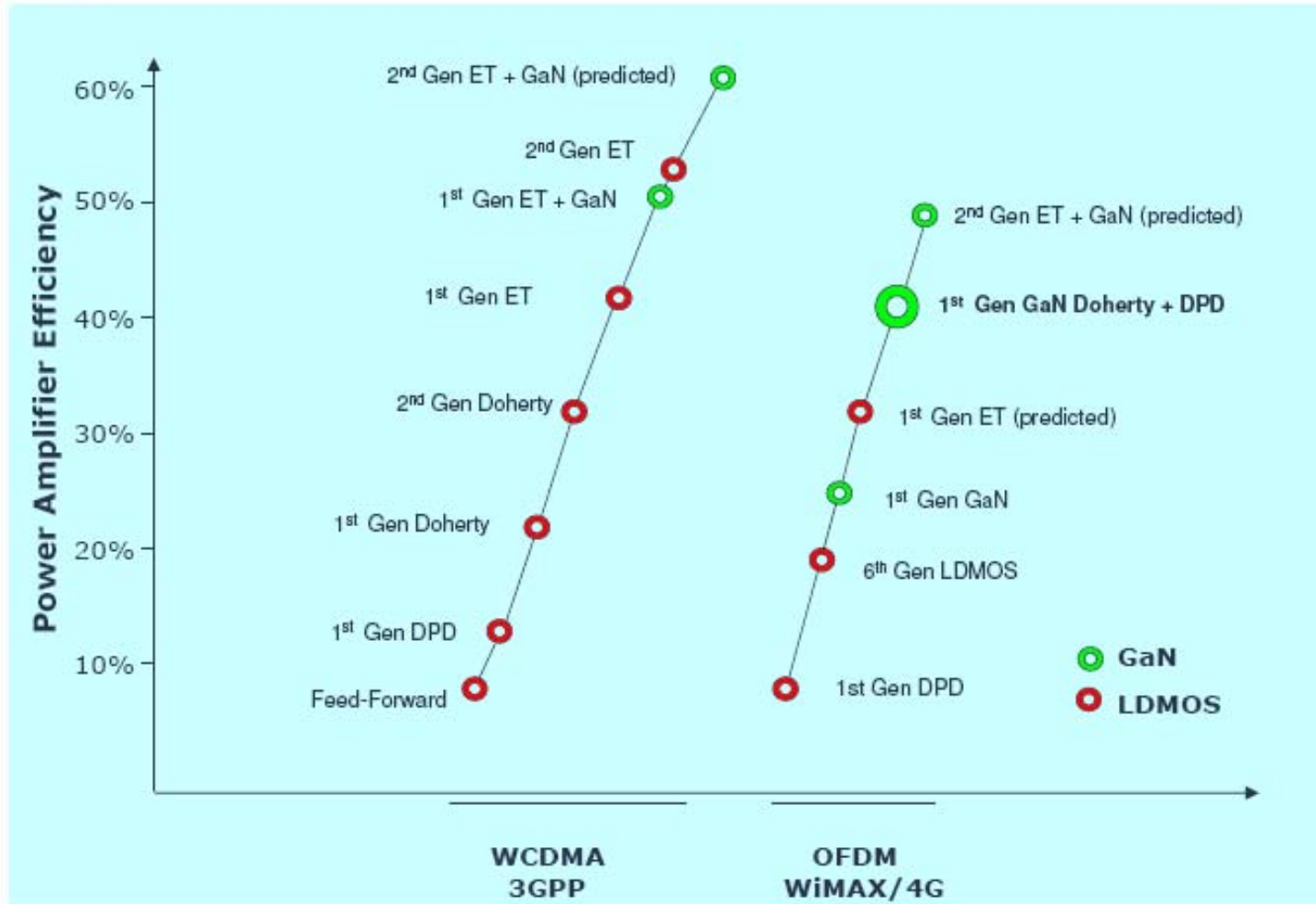
TGF4124-EPU RF Performance at  $F = 2.3 \text{ GHz}$   
 $V_d = 8.0 \text{ V}$ ,  $V_g = -1.1 \text{ V}$ ,  $I_q = 2.17 \text{ A}$  and  $T_A = 25^\circ\text{C}$



# Design and Technology Issues

- Design Drivers:
  - Low noise : Noise Figure, Gain, Linearity
  - High power: Efficiency, Output Power, Bandwidth, Linearity
- Main Technologies:
  - Low Noise: CMOS (Silicon), Bi-CMOS (Silicon and Silicon-Germanium), GaAs
  - High Power: LDMOS (Silicon), MESFET (GaN and GaAs)
- (Other) Issues: Cost, Packaging (parasitics), Very Wideband Performance

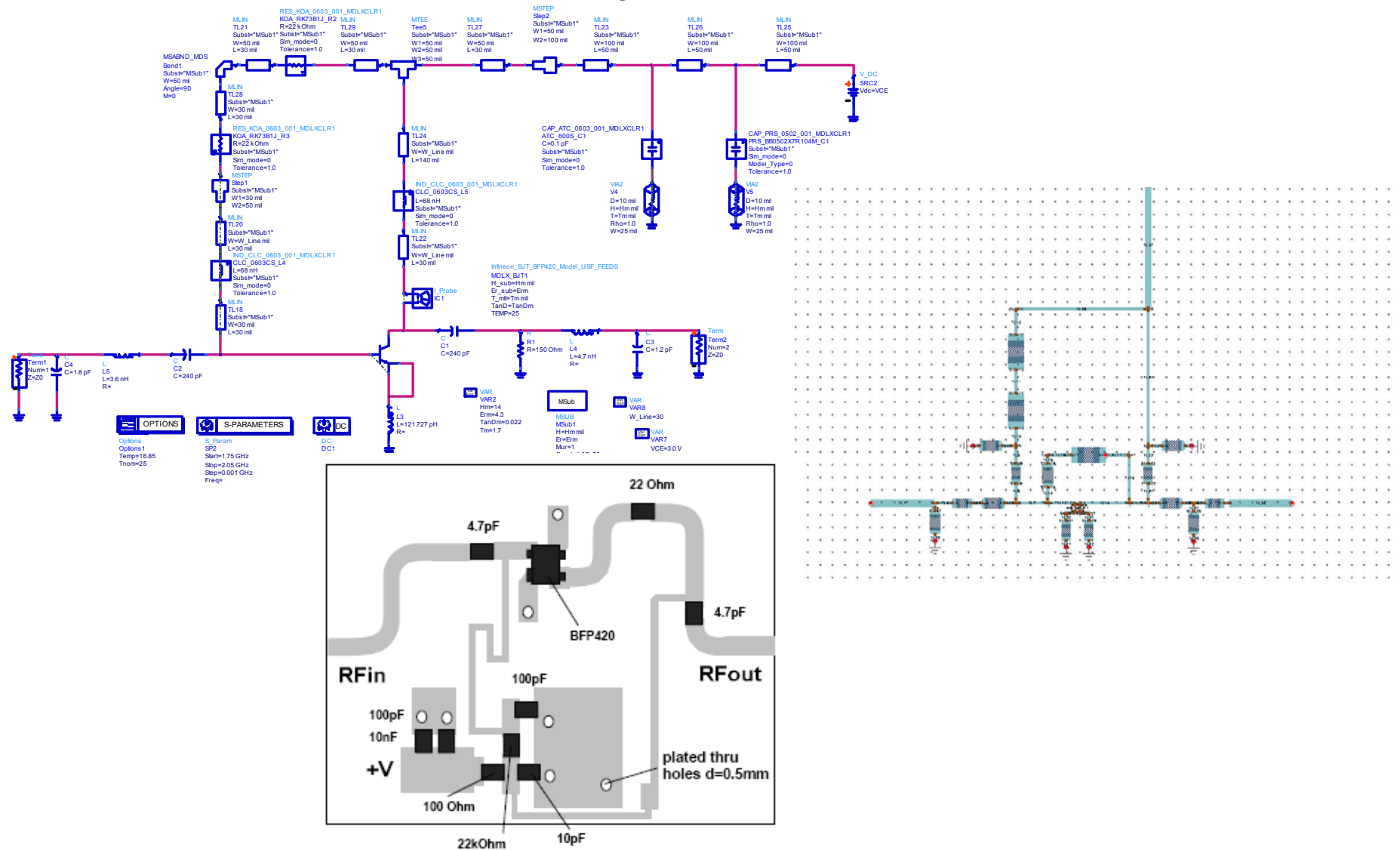
# Design and Technology Issues



# Design Approach – Low Noise Amplifiers

- The basic steps:
  - Prepare to compromise
  - Select the transistor(s) and other components
  - Find the best CAD models available for the parts
  - Select the DC operating condition
  - Design input and output impedance matching networks

# Design Approach – Low Noise Amplifiers



# Design Approach – Low Noise Amplifiers

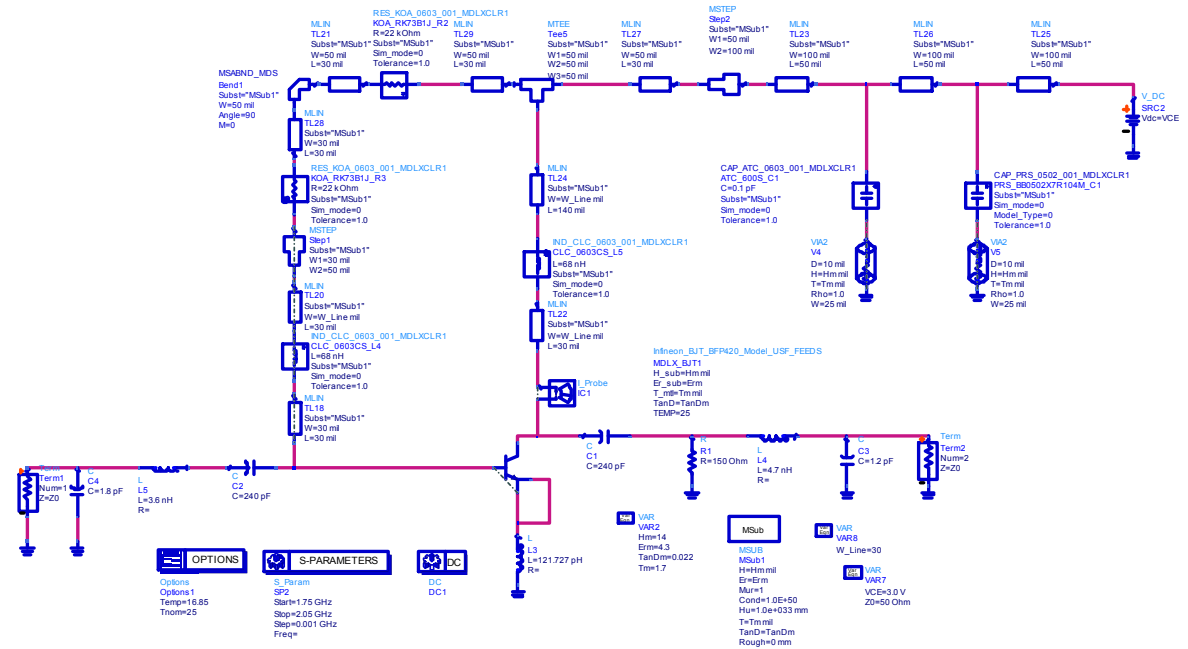
- Why compromise?

# Design Approach – Low Noise Amplifiers

- Selecting the components

# Design Approach – Low Noise Amplifiers

- Why are computer-aided-design (CAD) models so important?

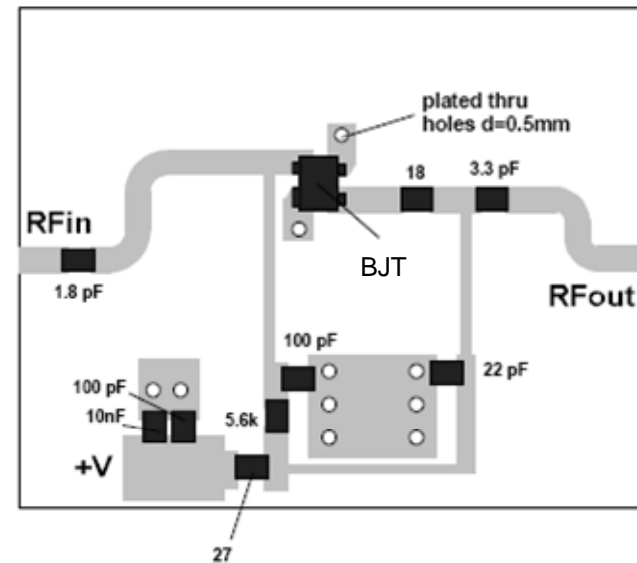
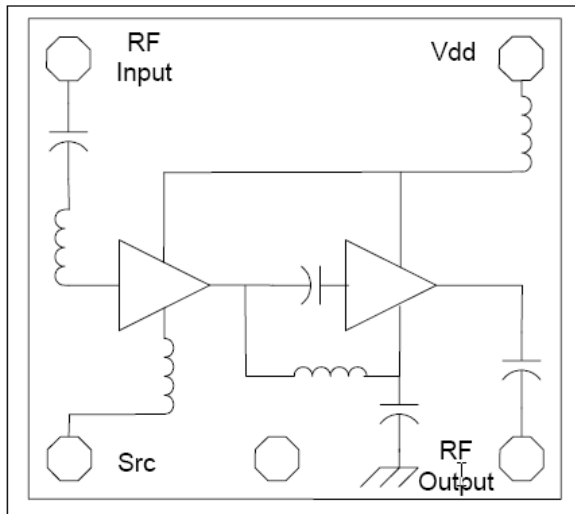




# Design Approach – Low Noise Amplifiers

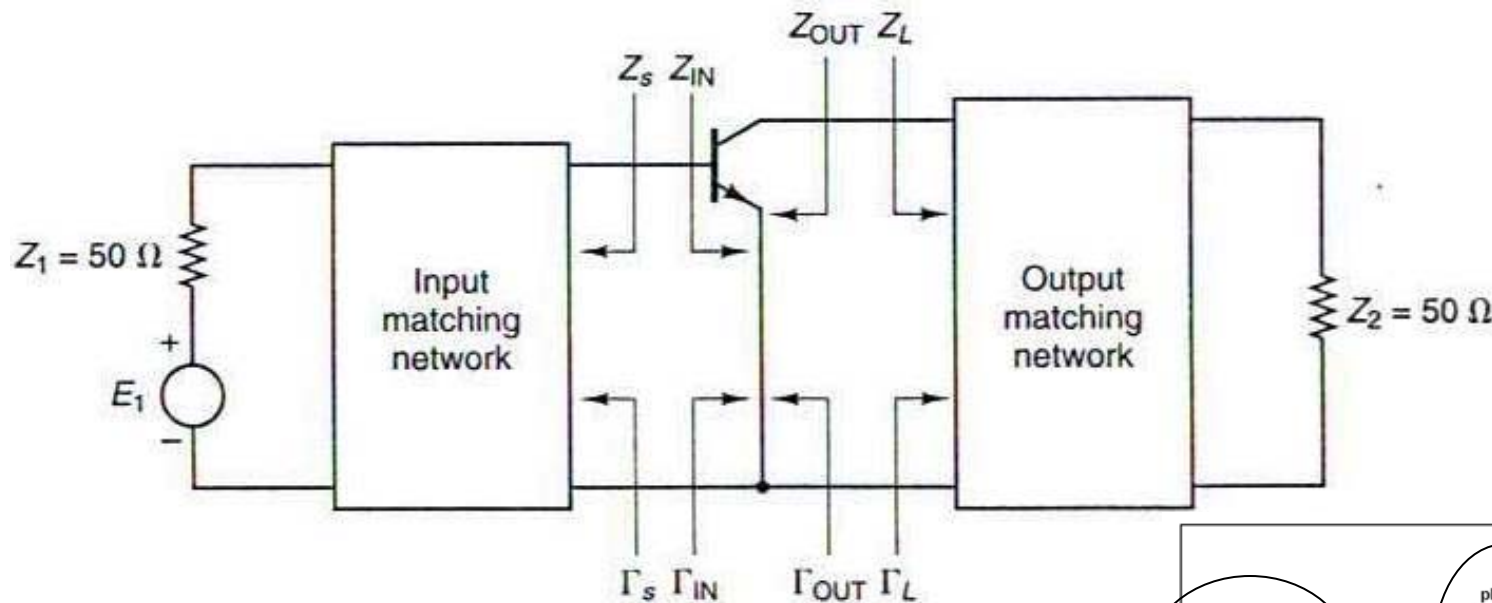
- DC operating condition:

*Functional Block Diagram*

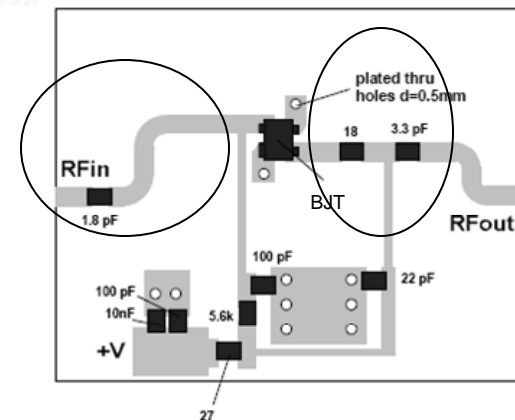


# Design Approach – Low Noise Amplifiers

- Matching Networks



$$G_T = \frac{1 - |\Gamma_s|^2}{|1 - \Gamma_s \Gamma_{IN}|^2} |S_{21}|^2 \frac{1 - |\Gamma_L|^2}{|1 - S_{22} \Gamma_L|^2}$$



# Amplifiers – Conclusions

- System-level specifications flow down to amplifier requirements → important for system designer to understand technology options and capabilities of each
- Impact on system design
  - Range – transmit power of PA and noise figure & gain of LNA
  - Battery life – PAs are one of the biggest consumers